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Working principle description of the wireless passive EM transduction pressure sensor

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Abstract. The development of a new passive wireless pressure sensor, based on an electromagnetic transduction approach, is reported. The sensing element is a flexible high resistivity silicon membrane located above a coplanar quarter-wavelength resonator. The comprehensive coverage of the physical bases is beyond the scope of this paper. For the remote extraction of the applied pressure value, the passive pressure sensor is connected to a broadband horn antenna via a coaxial delay line. When interrogated by a frequency modulated continuous wave radar, the level of the backscattered signal changes versus the pressure applied to the proof body. Through this interrogation principle, the sensor provides load impedance that is reflected back to the radar reader: the measured dynamic is about 0.8 dBm/bar. This completely passive and wireless pressure telemetry micro-sensor has been designed, fabricated and characterized, thereby eliminating the need for contact, signal processing circuits, and power supplies needed by conventional active sensors.

1 Introduction

Today, more and more growing demands of the industry for implementation of completely passive sensor system are observed. In fact, in many rising applications a wired connection between the sensor and the data processing system cannot be installed and simplicity of the sensor is desirable. There is a need for wireless telemetry system that requires no physical contact with the sensor and no active elements such as power supplies, signal processing circuits, or batteries. In the past, several systems consisting of an active battery-powered sensor unit have been presented [1,2]. The major problem of these active-based systems is the necessary energy source, which limits the lifetime, performance, cost and may add significant weight and volume to the sensor unit. Other passive systems have been also developed such as Radio Frequency IDentification (RFID) tags and Surface Acoustic Wave (SAW) based sensors [3,4]. But passive RFID tags present the disadvantage of short reading range while the main disadvantages of acoustic sensors are sensitivity to contamination, difficulty of calibration, and the need for optimized signal processing algorithm [5]. Moreover, due to the fact that the RF interrogation signal has to cover twice the distance between the transceiver and the sensor unit without amplification, the attenuation is doubled compared to conventional battery-powered sensor systems [6]. Thus, the signal amplitude received by the transceiver unit is many orders lower than the amplitude of the transmitted interrogation signal. In this paper, the development of a new passive and wireless pressure sensor, based on an electromagnetic transduction approach, is reported. The sensor design covers different disciplines such as microwaves, materials, micro-fabrication, and mechanics. The comprehensive coverage of the physical bases is beyond the scope of this paper and new measurement results dealing with the wireless interrogation technique of the pressure sensor unit are presented. The sensor cell can be considered as a passive scatterer having a reflectivity (or radar cross-section) that varies with – or is controlled by – the applied pressure. These measurements show that the proposed wireless passive system (composed of: sensor, antenna and radar) is functional and can be used for remote measurements of the applied pressure.

The paper is structured as follows. In Section 2 the design approach of the pressure micro-sensor is reported. In Section 3, the detailed working principle is described. Measurement results are shown and discussed in Section 4. Finally conclusions and perspectives of this research work are presented in Section 5.

2 The EM pressure sensor

2.1 The concept

Pressure sensors generally consist of a flexible mounted diaphragm which undergoes a deflection due to different
pressure between both sides. Recently we have presented a new pressure sensor based on an Electromagnetic (EM) transduction approach [7–9]. The principle of the sensor is based on the change of an electromagnetic field distribution in the interface between a planar resonator and a membrane placed above. In this region, the EM field is evanescent and consequently, a small deflection of the membrane due to the applied pressure modifies significantly the EM field distribution: a shift in the microwave resonant frequency of the resonator occurs and from this shift estimation of the applied pressure may be derived. To fabricate a high-sensitivity sensor based on this principle, we must achieve a high mechanical/electromagnetic coupling effect for very small membrane displacement (few micrometers).

We settled an operating (resonant) frequency of \( f_0 = 30 \text{ GHz} \). At this frequency, the dimensions of microwave circuits are about few millimeters. So we intend to realize rather compact pressure sensors for various applications (automotive, aeronautical). It is necessary to note also that we are in perfect adequacy with frequencies ranges used for Radar system: Frequency Modulated Continuous Wave (FMCW) Radar can remotely interrogate the passive pressure sensor at a range of some tens of meters. The sensor unit is then viewed as a passive scatterer having radar cross-section that varies with the applied pressure.

### 2.2 Sensor structure

As shown in Figure 1, the pressure sensor is composed of four parts:

- **The membrane**: the important element of the EM transduction is high resistivity silicon (>3 k\( \Omega \) cm). This material has a dielectric permittivity of 11.6 and is chosen due to its well-known mechanical properties as well as the fabrication process. The geometrical shape of the membrane is given by the geometry of the cavity where the planar resonator is deposited. The silicon membrane will be sealed to Pyrex by an anodic bonding.

- **The substrate** is made of Pyrex of type borosilicate (CORNING 7740). This material presents weak RF losses with a dielectric permittivity of 4.6. This material allows an easy assembly with the silicon. Its dilution coefficient is more or less the same as that of the silicon membrane. The Pyrex is resistant to thermal shocks, resisting the acid baths and can be used for high temperature applications.

- **The resonator** consists of a quarter-wave coupled-line coplanar filter (see Sect. 2.3). The ideal conductive material remains the gold considering its weak electric resistivity which tends to minimize the effect of the skin depth. The gold is also characterized by its excellent resistance to chemical baths. However, in our case, we cannot use this kind of metal because in the Pyrex/silicon bonding step, we rise the temperature up to 370 °C and thus problems of gold diffusion may take place. Our choice settles on another metal: Aluminum (Al), which is resistant to the chemical baths as well as gold. This metal presents weak resistive losses. The aluminum thickness is fixed to 1 \( \mu \text{m} \).

- **The air gap** is the thin layer between the resonator and the silicon membrane placed above. In this gap the EM field is evanescent.

### 2.3 Sensor design and dimensions

The resonator is realized in coplanar technology. A coplanar structure presents the advantage to have an EM field distribution which is in adequacy with the EM transduction approach and requires planar pads (the ground and the signal line are in the same plane). Moreover, in comparison with the other transmission line technologies, the coplanar one presents more design flexibility: for the same impedance value, one can have several possible dimensions. Coplanar transmission lines offer a better compliance to perform RF measurements.

The resonator is composed of a quarter-wave coupled-line filter operating at \( f_0 = 30 \text{ GHz} \). The quarter-wave coupled-line filter can present the same performances (bandwidth, selectivity, quality factor) as an interdigitated filter but it will have bigger dimensions. We adopt here a structure based on a filter with only one resonant element to enhance the interaction of the silicon membrane with the evanescent EM field confined above the coplanar resonator. The sensor topology is shown in Figure 2. The parameters \( W, G, S, L \) and \( \lambda_0 \) represent respectively the coplanar line width, the coplanar line gap, the coplanar coupled-line gap, the central line length and the guided wavelength of the fundamental mode in the coplanar line at the operating frequency \( f_0 \).

The design of the millimeter-wave coplanar resonator is done according to the classical filter design theory [10, 11]. The coplanar quarter-wave coupled-line resonator is designed to have a resonant frequency \( f_0 = 30 \text{ GHz} \) for
3 How does the EM transduction pressure sensor work?

This section aims at (1) bringing comprehension elements of the physical phenomenon related to the electromagnetic transduction and (2) verifying this principle without a complicated design step. The working principle is described by means of an analytical model by considering a dielectric membrane getting closer to a coplanar waveguide transmission line with a uniform movement. This study is based on an integral and variational electromagnetic modeling theory called the Transverse Resonance Method [12]. It allows the extraction of key parameters such as: the effective relative permittivity of the waveguiding structure, the sensor fundamental resonant frequency and the EM field distribution. Figure 4 shows a cross-sectional view of the coplanar waveguide under study. The boundary conditions are unchanged by translation along the longitudinal Oz-axis. For simplicity reasons in the theoretical developments, the dispersion equation is derived for a coplanar line inserted in artificial rectangular metallic waveguide. This waveguide introduces boundary conditions that are not present in the original structure shown in Figure 2. However, since the electromagnetic energy of the fundamental mode in the coplanar line is known to be very small in regions close to these boundaries, the artificially inserted metallic waveguide does not significantly participate in the dispersion phenomena while it allows simplifying the theoretical developments. Moreover the metallic and dielectric losses are neglected in this simple electromagnetic modeling. The coplanar line is located on the discontinuity plane xOz; it consists of a metallic surface with two infinite parallel longitudinal slots. The high resistivity silicon membrane with thickness \( h_3 \) and relative permittivity \( \varepsilon_r \) is placed above the coplanar line. Between the coplanar line and the membrane, we have a thin air gap region of thickness \( h_2 \) and relative permittivity \( \varepsilon_r \); in this region the EM field is evanescent at the operating frequency. The dielectric (Pyrex) substrate of thickness \( h_1 \) on which the coplanar line is micro-machined is characterized by relative permittivity \( \varepsilon_r \) and thickness \( h_1 \).

A good approximation of the guided wavenumber \( \beta \) of the fundamental mode in this coplanar waveguiding structure is solution of the following dispersion equation (see, e.g., [13,14] for details on the Transverse Resonance Method applied to planar waveguides):

\[
0 = \sum_{n=1,3,5,...} \frac{\beta^2}{(n^2 + \beta^2)} + \sin^2 \left( \frac{n \pi s + w}{2} \right) \left( \sin \frac{n \pi w}{2} \right)^2 \times \left[ Y_n^{TE} + Y_n^{TM} \right],
\]

where

\[
Y_n^{\alpha} = Y_n^{\alpha,1n} \coth[p_{1n}h_1] \quad \text{and} \quad Y_n^{\alpha} = Y_n^{\alpha,2n} \coth[p_{2n}h_2] + Y_n^{\alpha,3n} \coth[p_{3n}h_3] \quad (2)
\]
Fig. 5. (Color online) Variation of the effective relative permittivity of the coplanar line shown in Figure 4 versus the air gap thickness $h_2$ (i.e., the distance between the coplanar line and the silicon membrane interface).

with $\alpha = TE, TM$ and, for $i = 1, 2, 3$:

$$Y_{M, in}^{TE} = \frac{p_{in}}{j\omega \mu_0},$$

$$Y_{M, in}^{TE} = \frac{j\omega \varepsilon_0 \varepsilon_{ri}^2}{p_{in}},$$

where $p_{in}^2 = \left(\frac{n \pi}{a}\right)^2 + \beta^2 - k_0^2 \varepsilon_{ri}$.

In equation (3) $k_0$ denotes the free-space wavenumber ($k_0 = 2\pi f_0/c$ where $c$ is the free-space celerity of light).

In the dispersion equation (1) we can substitute $\beta$ by $\pi/L$ and consequently, from resolution of the resulting resonant equation, derive the resonant frequency $f_0$ of the first resonant mode. In particular, we can predict the resonant frequency when varying the air gap thickness $h_2$ and then, estimate the frequency shift when applying a pressure on the silicon membrane (the membrane displacement is assumed to be uniform above the coplanar resonator).

From resolution of the resonant equation with dimensions given in the caption of Figure 3 with $h_1 = 1$ mm and $h_3 = 0.4$ mm, a shift of 6.3 GHz in the millimeter-wave resonant frequency of the coplanar resonator is numerically found when varying the air gap thickness $h_2$ from 0.3 $\mu$m to 3 $\mu$m. This high sensitivity of the resonant frequency to such small membrane deflection is the consequence of the rapid variation of the effective relative permittivity $\varepsilon_{ref} = (\beta/k_0)^2$ when varying the air gap thickness (see Fig. 5). It results from a strong perturbation of the evanescent EM field in this region when approaching the silicon membrane interface to the transmission line.

The proposed sensor is very sensitive to the air gap variation but not to the technological parameters: the different process steps are well known (Pyrex etching, anodic bonding, and membrane realization). This process flow has proven its reliability in the fabrication of capacitive pressure sensors [15]. Fixed membrane sensors are used as reference sensors for the calibration step. Since the technological dispersion is limited, due to the well-known process, the difficulties in sensor calibration are consequently minimized.

In Figure 6, the computed magnitude of the electric field is displayed for various air gap thicknesses (see Fig. 5 for the definition of $A, B, C$ and $D$ points). We observe stationary waves in the silicon membrane ($p_{2n}$ is pure imaginary number for some low order $n$) and evanescent waves in the air gap region ($p_{3n}$ is real for any $n$). Moreover, when approaching the membrane to the coplanar line (or equivalently decreasing the air gap thickness) the electric field migrates gradually from the slots of the coplanar line to the air gap region and the electromagnetic coupling between the coplanar line and the membrane increases: more and more electric energy penetrates inside the dielectric.
membrane and the resulting relative effective permittivity increases (as found theoretically, see Fig. 5). The first resonant frequency \( c / \sqrt{\varepsilon_{\text{ref}}} L \) of the corresponding coplanar quarter-wave coupled-line resonator will then significantly decrease when approaching the membrane to the coplanar line from 3 \( \mu m \) to 0.3 \( \mu m \). Since the effective permittivity of coplanar transmission line is found to be highly dependent on the air gap thickness (or on the applied pressure), passive pressure sensor based on the proposed resonator is expected to have high sensitivity.

### 4 Measurement results

Pressure sensors with 50 \( \mu m \) thick silicon circular membrane (2800 \( \mu m \) diameter) have been fabricated. Measurement results under real working conditions, obtained from a specific RF/pressure measurement bench, have been reported and have revealed a high sensitivity of 370 MHz/bar in Ka band. Detailed discussion concerning the electromagnetic characterization of the sensor is presented in previous work [16].

Figure 7 shows the spectral sensor response when no pressure is applied. The measured return loss reveals a resonant frequency \( f_r = 39.46 \text{ GHz} \) with a magnitude of \(-15.34 \text{ dB}\). Previous work [16] presented a parametric study in which the relation between the membrane thickness and the resonant frequency is established. The resonant frequency of 39.46 GHz is in adequacy with the membrane thickness of 50 \( \mu m \).

Here new measurement results dealing with the wireless interrogation technique are presented. The pressure sensor is interrogated in indoor environment using FMCW radar reader. As shown in Figures 8 and 9, the passive pressure sensor is connected to a broadband horn antenna via a coaxial (delay) line of 1 m of length. The other port is loaded by 50 \( \Omega \) matched impedance. The sensor is viewed as load impedance depending on the applied pressure.

The sawtooth FM signal of the reader, in Ka band, is transmitted in direction of the sensor antenna and mixed...
with the backscattered signal to produce few ten kHz (beat frequency) radar signal. As expected, we have observed that the level of the backscattered signal changes in response to applied pressure. In particular, between 0 and 2.5 bars we obtained from Figure 10 a measured sensitivity close to 0.8 dBm/bar.

These measurements show that the proposed wireless system (composed of passive sensor, antenna and FMCW radar) is functional and allows the remote measurement of the applied pressure with no need for signal processing circuits, power supplies or batteries to be integrated within the sensor units. The sensor unit is then viewed as a passive scatterer having a reflectivity (or radar cross-section) that varies with – or is controlled by – the applied pressure.

5 Conclusion

In conclusion, this paper presents a detailed working overview of the EM pressure sensor and brings a proof of concept of an original remote pressure measurement technique using EM transduction passive sensor as electromagnetic scatterer: the applied pressure on the EM passive sensors modifies their radar echo magnitude. Using the FMCW radar interrogation method, the pressure can then be remotely measured. Experimental results presented here demonstrate the feasibility of the remote physical quantities measurement from the backscattered echo of EM passive sensors. For the first time, the functioning and so the feasibility of this passive wireless system (EM pressure sensor connected to the antenna) under real working condition is demonstrated. Using this wireless interrogation technique, sensitivity of 0.8 dBm/bar is measured for the very first sensor prototype.

Future work will be the optimization of the pressure measurement unit. Solutions for transportable version of the whole system are being studied. The optimized system will be used for the validation of long interrogation range (around 30 m). Identification techniques, for the pressure cell identification among wireless sensor network, are also under investigation.

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